250 V, 40 A SWITCHMODE™ Schottky Power Rectifier

Features

- 250 V Blocking Voltage
- Low Forward Voltage Drop, $V_F = 0.86 \text{ V}$
- Soft Recovery Characteristic, T_{RR} < 35 ns
- Low Reverse Current, $I_R = 30 \mu A$
- Stable Switching Performance Over Temperature
- Pb-Free Packages are Available

Benefits

- Reduces or Eliminates Reverse Recovery Oscillations
- Minimizes Need for EMI Filtering
- Reduces Switching Losses
- Improved Efficiency

Applications

- Power Supply
- Power Management
- Automotive
- Instrumentation

Mechanical Characteristics

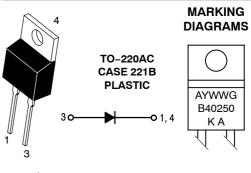
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Epoxy Meets UL 94 V-0 at 0.125 in

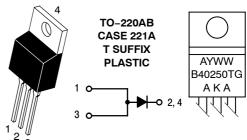


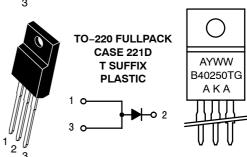
ON Semiconductor®

http://onsemi.com

SCHOTTKY RECTIFIER 40 AMPERES, 250 VOLTS







B40250 = Device Code

T = 3 pins

A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package KA, AKA = Polarity Designator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	250	V
Average Rectified Forward Current (Rated V_R) T_C = 82°C MBR40250, MBR40250T (Rated V_R) T_C = 46°C MBRF40250T	I _{F(AV)}	40	А
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz) T_C = 82°C MBR40250, MBR40250T (Rated V_R , Square Wave, 20 kHz) T_C = 46°C MBRF40250T	I _{FRM}	80	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 20 kHz)	I _{FSM}	150	Α
Storage Temperature	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	-65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/µs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Maximum Thermal Resistance Junction-to-Case MBR40250(T) MBRF40250 Junction-to-Ambient MBR40250(T) MBRF40250 MBRF40250	R _{θJC} R _{θJA}	2.0 3.0 60 50	°C/W

ELECTRICAL CHARACTERISTICS

Rating	Symbol	Value	Unit
	V _F 20 A, T _C = 25°C 0 A, T _C = 125°C 40 A, T _C = 25°C 0 A, T _C = 125°C	0.86 0.71 0.97 0.86	V
	tage, T _C = 25°C age, T _C = 125°C	0.03 30	mA
Maximum Reverse Recovery Time $I_F = 1.0 \ A, \ di/dt = 50 \label{eq:IF}$	A/ μ s, T _C = 25°C	35	ns

DYNAMIC CHARACTERISTICS

F					
	Capacitance	V_R = -5.0 V, T_C = 25°C, Frequency = 1.0 MHz	C _T	500	pF

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

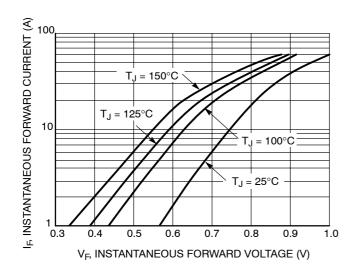
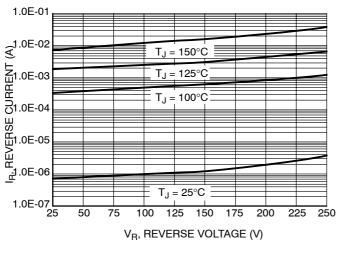


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage



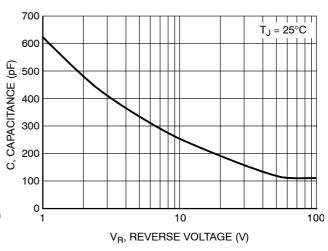
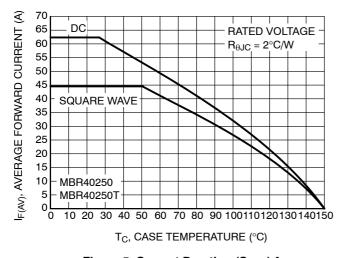


Figure 3. Typical Reverse Current

Figure 4. Typical Capacitance



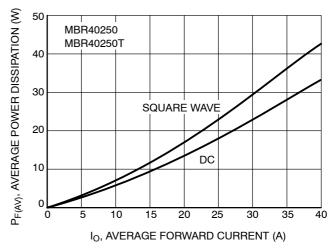
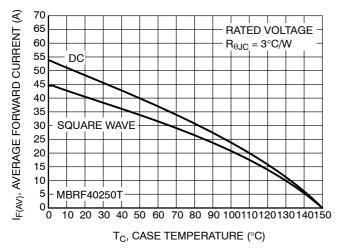


Figure 5. Current Derating (Case) for MBR40250 and MBR40250T

Figure 6. Forward Power Dissipation for MBR40250 and MBR40250T

TYPICAL CHARACTERISTICS



SQUARE WAVE

10

SQUARE WAVE

10

10, AVERAGE FORWARD CURRENT (A)

Figure 7. Current Derating (Case) for MBRF40250T

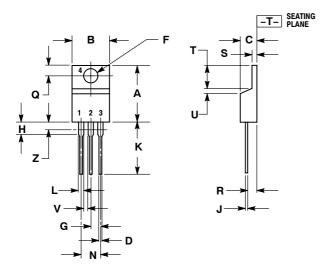
Figure 8. Forward Power Dissipation for MBRF40250T

ORDERING INFORMATION

Device	Package	Shipping [†]
MBR40250	TO-220AC	
MBR40250G	TO-220AC (Pb-Free)	50 Units / Rail
MBR40250T	TO-220AB	
MBR40250TG	TO-220AB (Pb-Free)	50 Units / Rail
MBRF40250T	TO-220 FULLPACK	
MBRF40250TG	TO-220 FULLPACK (Pb-Free)	50 Units / Rail

PACKAGE DIMENSIONS

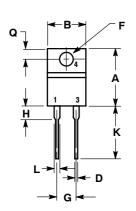
TO-220AB CASE 221A-09 **ISSUE AA**

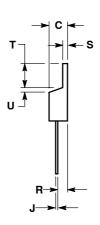


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
5	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

TO-220AC CASE 221B-04 ISSUE D





- OTLO.

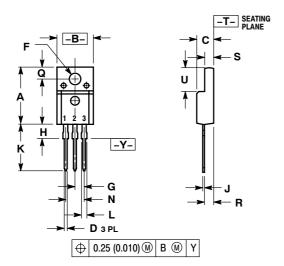
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
Т	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

PACKAGE DIMENSIONS

TO-220 FULLPACK

CASE 221D-03 ISSUE G



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH
 3. 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.625	0.635	15.88	16.12
В	0.408	0.418	10.37	10.63
C	0.180	0.190	4.57	4.83
D	0.026	0.031	0.65	0.78
F	0.116	0.119	2.95	3.02
G	0.100 BSC		2.54 BSC	
H	0.125	0.135	3.18	3.43
7	0.018	0.025	0.45	0.63
K	0.530	0.540	13.47	13.73
L	0.048	0.053	1.23	1.36
N	0.200 BSC		5.08 BSC	
œ	0.124	0.128	3.15	3.25
R	0.099	0.103	2.51	2.62
S	0.101	0.113	2.57	2.87
U	0.238	0.258	6.06	6.56

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